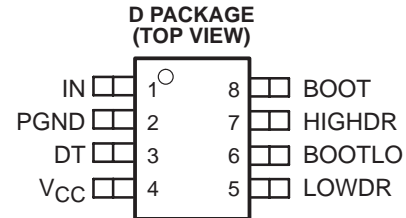


TPS2836, TPS2837 SYNCHRONOUS-BUCK MOSFET DRIVER WITH DEAD-TIME CONTROL

SLVS224B – NOVEMBER 1999 – REVISED AUGUST 2002

- Floating Bootstrap or Ground-Reference High-Side Driver
- Adaptive Dead-Time Control
- 50-ns Max Rise/Fall Times With 3.3-nF Load
- 2.4-A Typical Output Current
- 4.5-V to 15-V Supply Voltage Range
- TTL-Compatible Inputs
- Internal Schottky Bootstrap Diode
- Low Supply Current....3 mA Typical
- Ideal for High-Current Single or Multiphase Power Supplies
- – 40°C to 125°C Operating Virtual Junction-Temperature Range



description

The TPS2836 and TPS2837 are MOSFET drivers for synchronous-buck power stages. These devices are ideal for designing a high-performance power supply using switching controllers that do not have MOSFET drivers. The drivers are designed to deliver minimum 2-A peak currents into large capacitive loads. The high-side driver can be configured as ground-reference or as floating-bootstrap. An adaptive dead-time control circuit eliminates shoot-through currents through the main power FETs during switching transitions and provides high efficiency for the buck regulator.

The TPS2836 has a noninverting input, while the TPS2837 has an inverting input. These drivers, available in 8-terminal SOIC packages, operate over a junction temperature range of – 40°C to 125°C.

AVAILABLE OPTIONS

T _J	PACKAGED DEVICES
	SOIC (D)
– 40°C to 125°C	TPS2836D TPS2837D

The D package is available taped and reeled. Add R suffix to device type (e.g., TPS2836DR)

Related Synchronous MOS FET Drivers

DEVICE NAME	ADDITIONAL FEATURES	INPUTS	
TPS2830	ENABLE, SYNC and CROWBAR	CMOS	Noninverted
TPS2831			Inverted
TPS2832	W/O ENABLE, SYNC and CROWBAR	CMOS	Noninverted
TPS2833			Inverted
TPS2834	ENABLE, SYNC and CROWBAR	TTL	Noninverted
TPS2835			Inverted



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

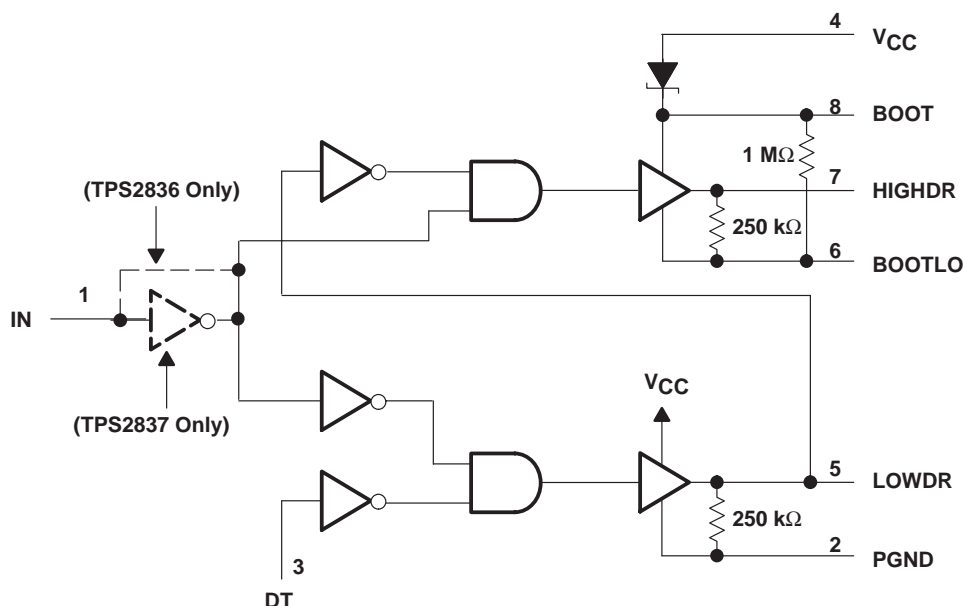
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TPS2836, TPS2837 SYNCHRONOUS-BUCK MOSFET DRIVER WITH DEAD-TIME CONTROL

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functional block diagram



Terminal Functions

TERMINAL NAME	NO.	I/O	DESCRIPTION
BOOT	8	I	Bootstrap terminal. A ceramic capacitor is connected between BOOT and BOOTLO to develop the floating bootstrap voltage for the high-side MOSFET. The capacitor value is typically between 0.1 μ F and 1 μ F.
BOOTLO	6	O	This terminal connects to the junction of the high-side and low-side MOSFETs.
DT	3	I	Dead-time control terminal. Connect DT to the junction of the high-side and low-side MOSFETs
HIGHDR	7	O	Output drive for the high-side power MOSFET
IN	1	I	Input signal to the MOSFET drivers (noninverting input for the TPS2836; inverting input for the TPS2837).
LOWDR	5	O	Output drive for the low-side power MOSFET
PGND	2		Power ground. Connect to the FET power ground.
VCC	4	I	Input supply. Recommended that a 1 μ F capacitor be connected from VCC to PGND.

TPS2836, TPS2837 SYNCHRONOUS-BUCK MOSFET DRIVER WITH DEAD-TIME CONTROL

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detailed description

low-side driver

The low-side driver is designed to drive low $r_{DS(on)}$ N-channel MOSFETs. The current rating of the driver is 2 A, source and sink.

high-side driver

The high-side driver is designed to drive low $r_{DS(on)}$ N-channel MOSFETs. The current rating of the driver is 2 A, source and sink. The high-side driver can be configured as a ground-reference driver or a floating bootstrap driver. The internal bootstrap diode is a Schottky for improved drive efficiency. The maximum voltage that can be applied between the BOOT terminal and ground is 30 V.

dead-time (DT) control

Dead-time control prevents shoot-through current from flowing through the main power FETs during switching transitions by controlling the turnon times of the MOSFET drivers. The high-side driver is not allowed to turn on until the gate drive voltage to the low-side FET is low, and the low-side driver is not allowed to turn on until the voltage at the junction of the power FETs (V_{drain}) is low; the TTL-compatible DT terminal connects to the junction of the power FETs.

IN

The IN terminal is a TTL-compatible digital terminal that is the input control signal for the drivers. The TPS2836 has a noninverting input; the TPS2837 has an inverting input.

absolute maximum ratings over operating free-air temperature (unless otherwise noted)[†]

Supply voltage range, V_{CC} (see Note 1)	–0.3 V to 16 V
Input voltage range: BOOT to PGND (high-side driver ON)	–0.3 V to 30 V
BOOTLO to PGND	–0.3 V to 16 V
BOOT to BOOTLO	–0.3 V to 16 V
IN	–0.3 V to 16 V
DT	–0.3 V to 30 V
Continuous total power dissipation	See Dissipation Rating Table
Operating virtual junction temperature range, T_J	–40°C to 125°C
Storage temperature range, T_{stg}	–65°C to 150°C
Lead temperature soldering 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: Unless otherwise specified, all voltages are with respect to PGND.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
D	600 mW	6.0 mW/°C	330 mW	240 mW

recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}	4.5		15	V
Input voltage	4.5		28	V



TPS2836, TPS2837

SYNCHRONOUS-BUCK MOSFET DRIVER

WITH DEAD-TIME CONTROL

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electrical characteristics over recommended operating virtual junction temperature range,
 $V_{CC} = 6.5 \text{ V}$, $C_L = 3.3 \text{ nF}$ (unless otherwise noted)

supply current

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{CC}	Supply voltage range		4.5		15	V
	Quiescent current	$V_{CC} = 15 \text{ V}$, $V_{(ENABLE)} = \text{LOW}$			100	μA
	Quiescent current	$V_{CC} = 15 \text{ V}$, $V_{(ENABLE)} = \text{HIGH}$		300	400	
	Quiescent current	$V_{CC} = 12 \text{ V}$, $f_{\text{SWX}} = 200 \text{ kHz}$, $C_{\text{HIGHDR}} = 50 \text{ pF}$, BOOTLO grounded, $C_{\text{LOWDR}} = 50 \text{ pF}$, See Note 2		3		mA

NOTE 2: Ensured by design, not production tested.

output drivers

PARAMETER			TEST CONDITIONS		MIN	TYP	MAX	UNIT
Peak output-current	High-side sink (see Note 4)	Duty cycle < 2%, $t_{\text{pw}} < 100 \mu\text{s}$ (see Note 3)	$V_{\text{BOOT}} - V_{\text{BOOTLO}} = 4.5 \text{ V}$, $V_{\text{HIGHDR}} = 4 \text{ V}$		0.7	1.1		A
			$V_{\text{BOOT}} - V_{\text{BOOTLO}} = 6.5 \text{ V}$, $V_{\text{HIGHDR}} = 5 \text{ V}$		1.1	1.5		
			$V_{\text{BOOT}} - V_{\text{BOOTLO}} = 12 \text{ V}$, $V_{\text{HIGHDR}} = 10.5 \text{ V}$		2	2.4		
	High-side source (see Note 4)	Duty cycle < 2%, $t_{\text{pw}} < 100 \mu\text{s}$ (see Note 3)	$V_{\text{BOOT}} - V_{\text{BOOTLO}} = 4.5 \text{ V}$, $V_{\text{HIGHDR}} = 0.5 \text{ V}$		1.2	1.4		A
			$V_{\text{BOOT}} - V_{\text{BOOTLO}} = 6.5 \text{ V}$, $V_{\text{HIGHDR}} = 1.5 \text{ V}$		1.3	1.6		
			$V_{\text{BOOT}} - V_{\text{BOOTLO}} = 12 \text{ V}$, $V_{\text{HIGHDR}} = 1.5 \text{ V}$		2.3	2.7		
	Low-side sink (see Note 4)	Duty cycle < 2%, $t_{\text{pw}} < 100 \mu\text{s}$ (see Note 3)	$V_{CC} = 4.5 \text{ V}$, $V_{\text{LOWDR}} = 4 \text{ V}$		1.3	1.8		A
			$V_{CC} = 6.5 \text{ V}$, $V_{\text{LOWDR}} = 5 \text{ V}$		2	2.5		
			$V_{CC} = 12 \text{ V}$, $V_{\text{LOWDR}} = 10.5 \text{ V}$		3	3.5		
	Low-side source (see Note 4)	Duty cycle < 2%, $t_{\text{pw}} < 100 \mu\text{s}$ (see Note 3)	$V_{CC} = 4.5 \text{ V}$, $V_{\text{LOWDR}} = 0.5 \text{ V}$		1.4	1.7		A
			$V_{CC} = 6.5 \text{ V}$, $V_{\text{LOWDR}} = 1.5 \text{ V}$		2	2.4		
			$V_{CC} = 12 \text{ V}$, $V_{\text{LOWDR}} = 1.5 \text{ V}$		2.5	3		
Output resistance	High-side sink (see Note 4)		$V_{\text{BOOT}} - V_{\text{BOOTLO}} = 4.5 \text{ V}$, $V_{\text{HIGHDR}} = 0.5 \text{ V}$				5	Ω
			$V_{\text{BOOT}} - V_{\text{BOOTLO}} = 6.5 \text{ V}$, $V_{\text{HIGHDR}} = 0.5 \text{ V}$				5	
			$V_{\text{BOOT}} - V_{\text{BOOTLO}} = 12 \text{ V}$, $V_{\text{HIGHDR}} = 0.5 \text{ V}$				5	
	High-side source (see Note 4)		$V_{\text{BOOT}} - V_{\text{BOOTLO}} = 4.5 \text{ V}$, $V_{\text{HIGHDR}} = 4 \text{ V}$				75	Ω
			$V_{\text{BOOT}} - V_{\text{BOOTLO}} = 6.5 \text{ V}$, $V_{\text{HIGHDR}} = 6 \text{ V}$				75	
			$V_{\text{BOOT}} - V_{\text{BOOTLO}} = 12 \text{ V}$, $V_{\text{HIGHDR}} = 11.5 \text{ V}$				75	
	Low-side sink (see Note 4)		$V_{\text{DRV}} = 4.5 \text{ V}$, $V_{\text{LOWDR}} = 0.5 \text{ V}$				9	Ω
			$V_{\text{DRV}} = 6.5 \text{ V}$, $V_{\text{LOWDR}} = 0.5 \text{ V}$				7.5	
			$V_{\text{DRV}} = 12 \text{ V}$, $V_{\text{LOWDR}} = 0.5 \text{ V}$				6	
	Low-side source (see Note 4)		$V_{\text{DRV}} = 4.5 \text{ V}$, $V_{\text{LOWDR}} = 4 \text{ V}$				75	Ω
			$V_{\text{DRV}} = 6.5 \text{ V}$, $V_{\text{LOWDR}} = 6 \text{ V}$				75	
			$V_{\text{DRV}} = 12 \text{ V}$, $V_{\text{LOWDR}} = 11.5 \text{ V}$				75	

NOTES: 3. Ensured by design, not production tested.

4. The pullup/pulldown circuits of the drivers are bipolar and MOSFET transistors in parallel. The peak output current rating is the combined current from the bipolar and MOSFET transistors. The output resistance is the $r_{\text{DS(on)}}$ of the MOSFET transistor when the voltage on the driver output is less than the saturation voltage of the bipolar transistor.

TPS2836, TPS2837
SYNCHRONOUS-BUCK MOSFET DRIVER
WITH DEAD-TIME CONTROL

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**electrical characteristics over recommended operating virtual junction temperature range,
 $V_{CC} = 6.5\text{ V}$, $C_L = 3.3\text{ nF}$ (unless otherwise noted) (continued)**

dead-time

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IH}	High-level input voltage	LOWDR	Over the V_{CC} range (see Note 3)	0.7 V_{CC}	1	V
V_{IL}	Low-level input voltage					V
V_{IH}	High-level input voltage	DT	Over the V_{CC} range	2	1	V
V_{IL}	Low-level input voltage					V

NOTE 3: Ensured by design, not production tested.

digital control terminals (IN)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IH}	High-level input voltage	Over the V_{CC} range	2		1	V
V_{IL}	Low-level input voltage					V

**switching characteristics over recommended operating virtual junction temperature range,
 $C_L = 3.3\text{ nF}$ (unless otherwise noted)**

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Rise time	HIGHDR output (see Note 3)	$V_{BOOT} = 4.5\text{ V}$, $V_{BOOTLO} = 0\text{ V}$			60	ns
		$V_{BOOT} = 6.5\text{ V}$, $V_{BOOTLO} = 0\text{ V}$			50	
		$V_{BOOT} = 12\text{ V}$, $V_{BOOTLO} = 0\text{ V}$			50	
	LOWDR output (see Note 3)	$V_{CC} = 4.5\text{ V}$			40	ns
		$V_{CC} = 6.5\text{ V}$			30	
		$V_{CC} = 12\text{ V}$			30	
Fall time	HIGHDR output (see Note 3)	$V_{BOOT} = 4.5\text{ V}$, $V_{BOOTLO} = 0\text{ V}$			50	ns
		$V_{BOOT} = 6.5\text{ V}$, $V_{BOOTLO} = 0\text{ V}$			40	
		$V_{BOOT} = 12\text{ V}$, $V_{BOOTLO} = 0\text{ V}$			40	
	LOWDR output (see Note 3)	$V_{CC} = 4.5\text{ V}$			40	ns
		$V_{CC} = 6.5\text{ V}$			30	
		$V_{CC} = 12\text{ V}$			30	
Propagation delay time	HIGHDR going low (excluding dead-time) (see Note 3)	$V_{BOOT} = 4.5\text{ V}$, $V_{BOOTLO} = 0\text{ V}$			95	ns
		$V_{BOOT} = 6.5\text{ V}$, $V_{BOOTLO} = 0\text{ V}$			80	
		$V_{BOOT} = 12\text{ V}$, $V_{BOOTLO} = 0\text{ V}$			65	
	LOWDR going high (excluding dead-time) (see Note 3)	$V_{BOOT} = 4.5\text{ V}$, $V_{BOOTLO} = 0\text{ V}$			80	ns
		$V_{BOOT} = 6.5\text{ V}$, $V_{BOOTLO} = 0\text{ V}$			70	
		$V_{BOOT} = 12\text{ V}$, $V_{BOOTLO} = 0\text{ V}$			60	
Propagation delay time	LOWDR going low (excluding dead-time) (see Note 3)	$V_{CC} = 4.5\text{ V}$			80	ns
		$V_{CC} = 6.5\text{ V}$			70	
		$V_{CC} = 12\text{ V}$			60	
Driver nonoverlap time	DT to LOWDR and LOWDR to HIGHDR (see Note 3)	$V_{CC} = 4.5\text{ V}$	40		170	ns
		$V_{CC} = 6.5\text{ V}$	25		135	
		$V_{CC} = 12\text{ V}$	15		85	

NOTE 3: Ensured by design, not production tested.

TPS2836, TPS2837 SYNCHRONOUS-BUCK MOSFET DRIVER WITH DEAD-TIME CONTROL

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TYPICAL CHARACTERISTICS

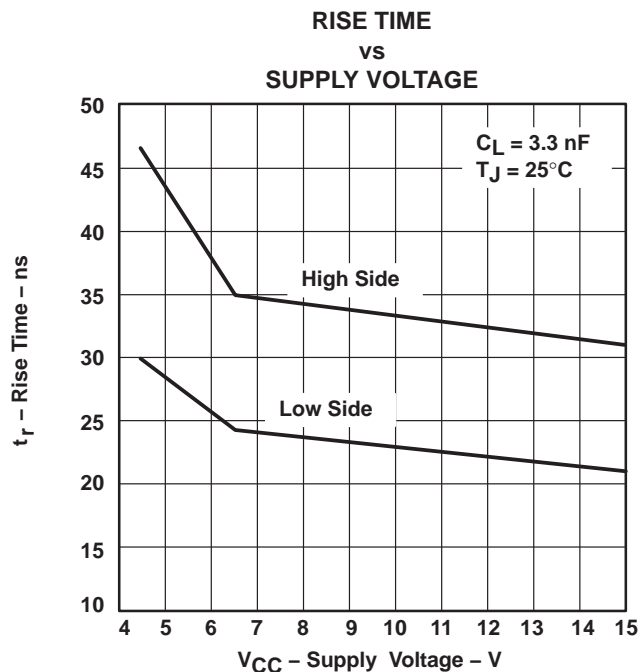


Figure 1

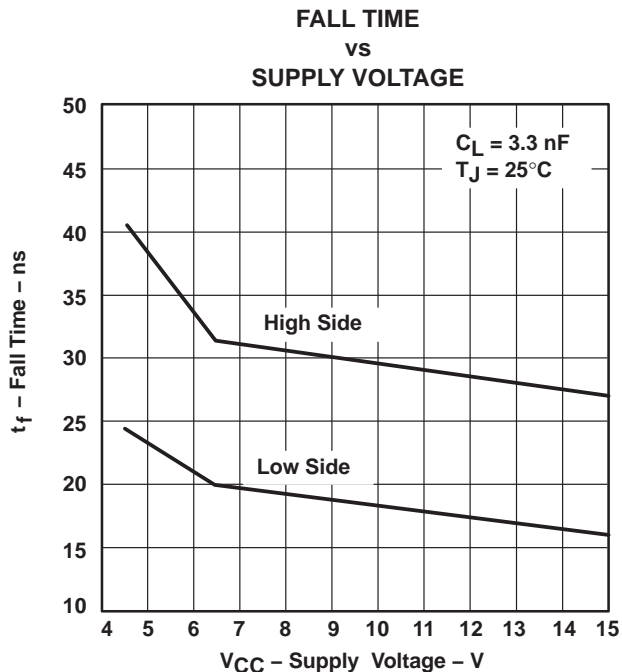


Figure 2

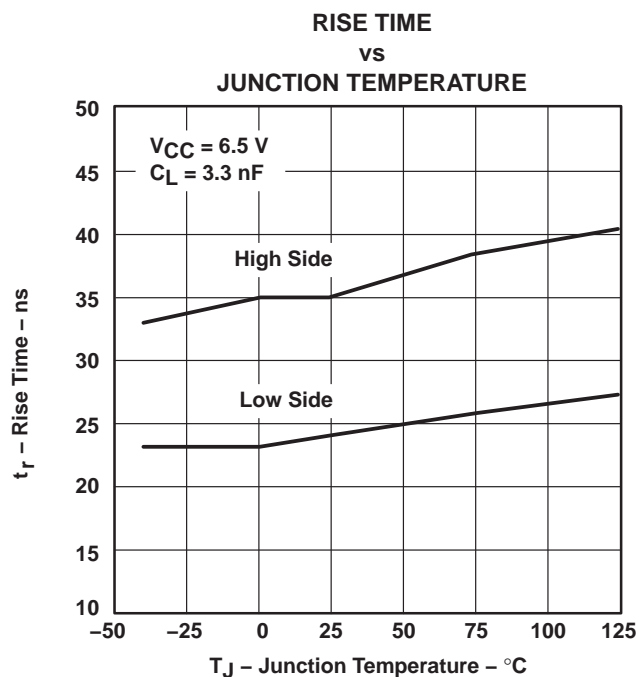


Figure 3

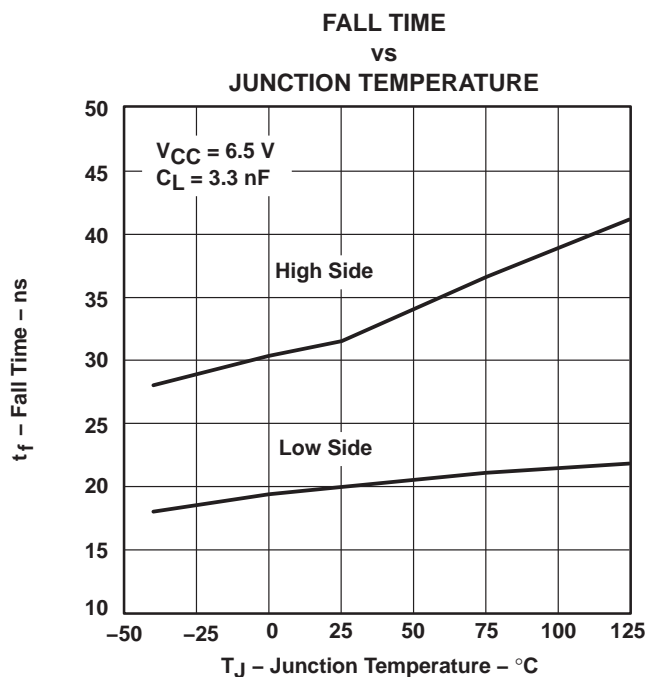


Figure 4

TPS2836, TPS2837 SYNCHRONOUS-BUCK MOSFET DRIVER WITH DEAD-TIME CONTROL

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TYPICAL CHARACTERISTICS

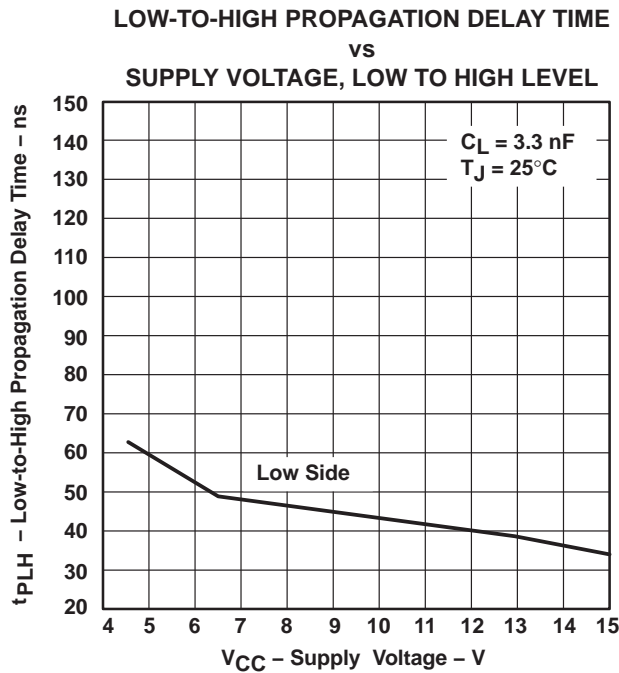


Figure 5

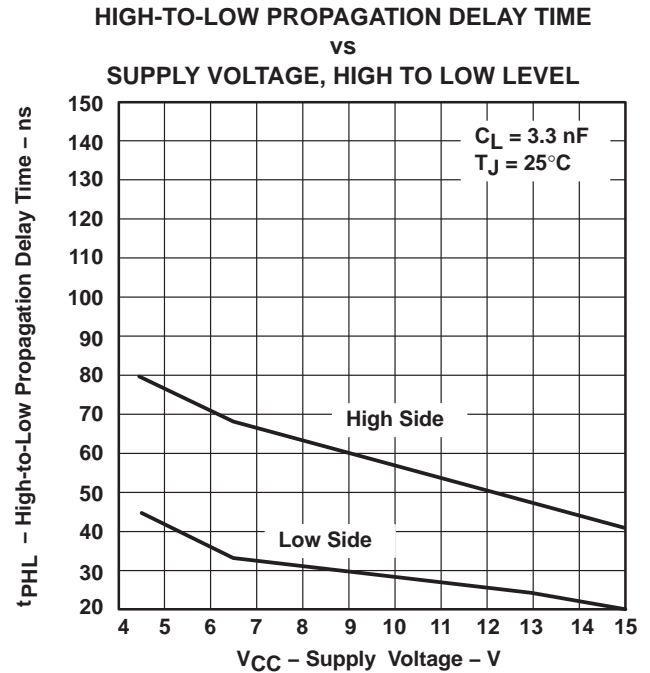


Figure 6

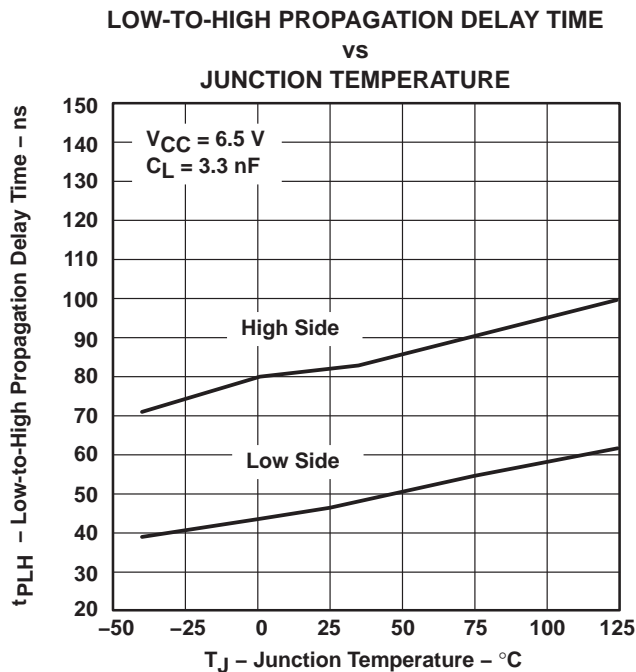


Figure 7

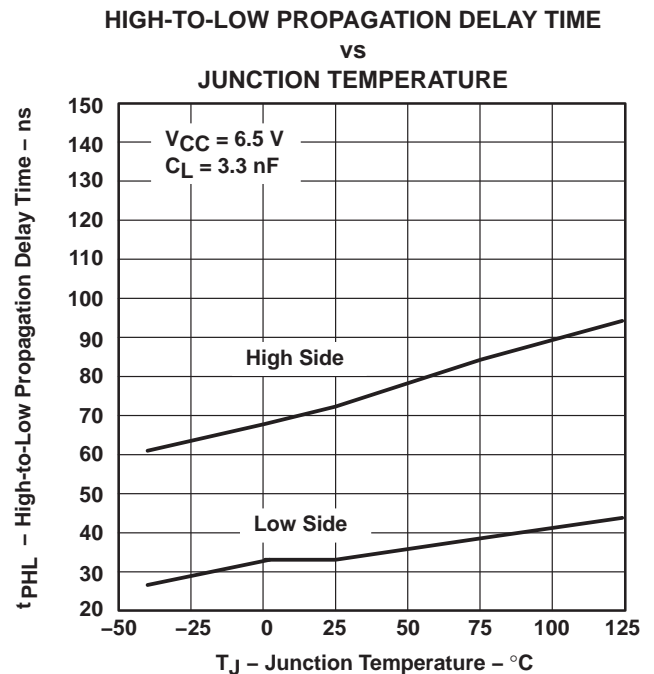


Figure 8

TPS2836, TPS2837 SYNCHRONOUS-BUCK MOSFET DRIVER WITH DEAD-TIME CONTROL

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TYPICAL CHARACTERISTICS

DRIVER-OUTPUT RISE TIME
vs
LOAD CAPACITANCE

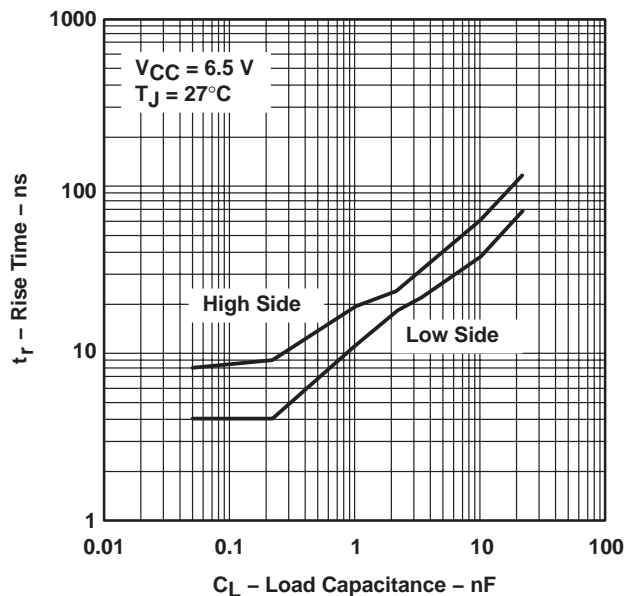


Figure 9

DRIVER-OUTPUT FALL TIME
vs
LOAD CAPACITANCE

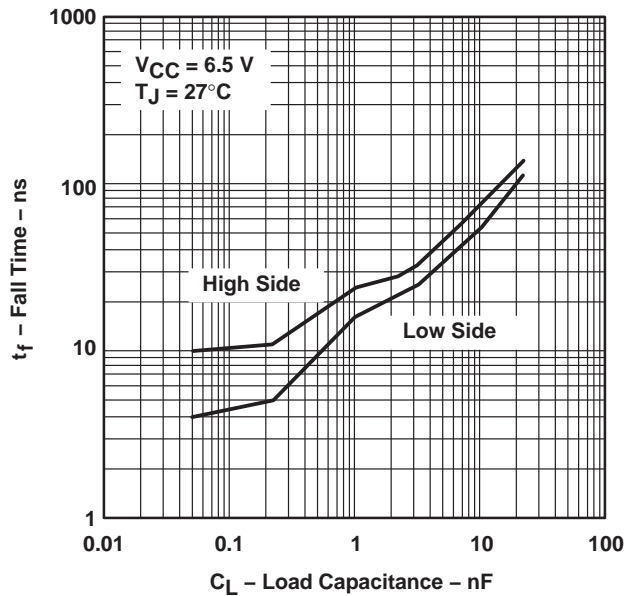


Figure 10

SUPPLY CURRENT
vs
SUPPLY VOLTAGE

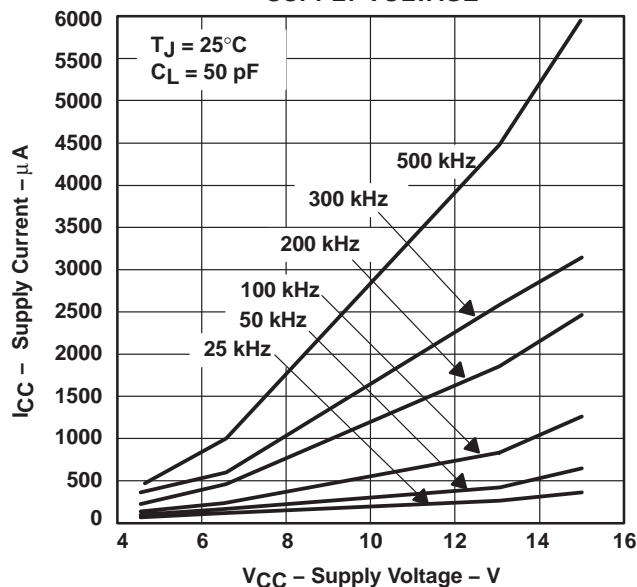


Figure 11

SUPPLY CURRENT
vs
SUPPLY VOLTAGE

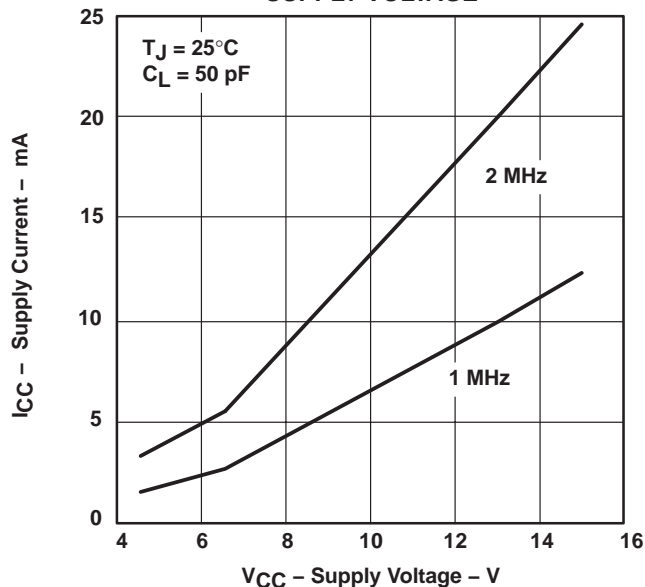


Figure 12

TYPICAL CHARACTERISTICS

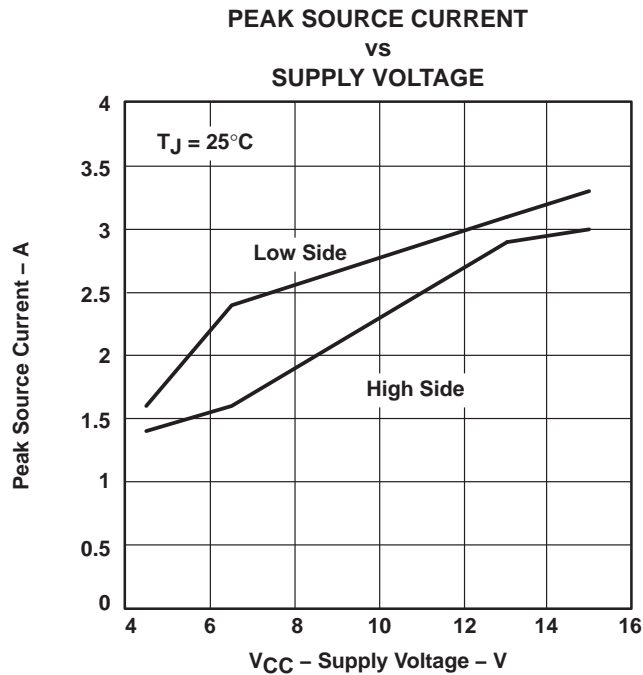


Figure 13

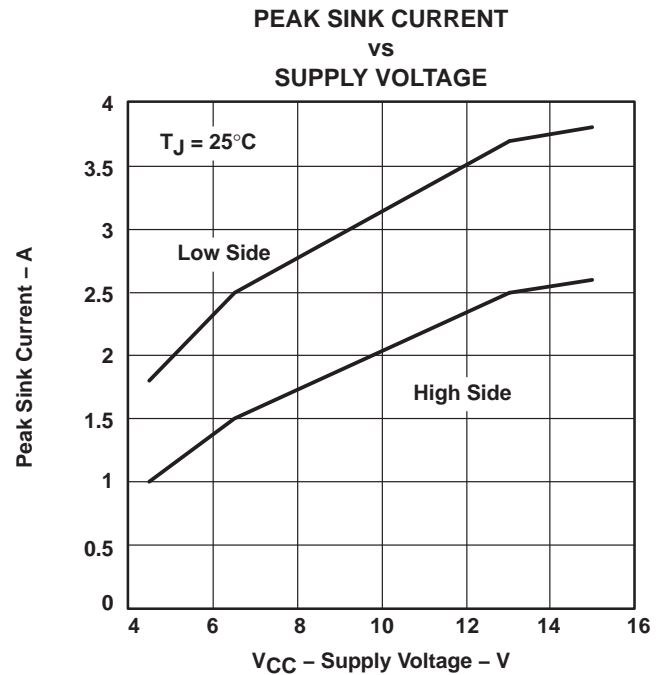


Figure 14

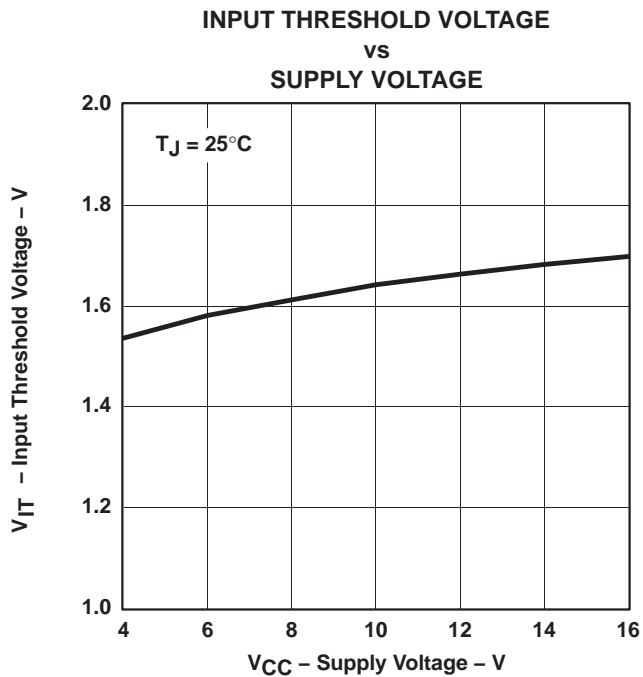


Figure 15

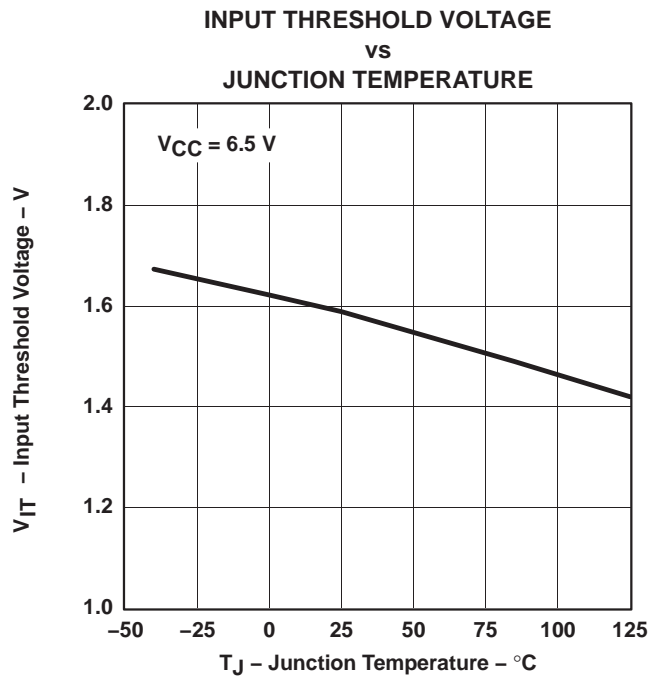


Figure 16

TPS2836, TPS2837 SYNCHRONOUS-BUCK MOSFET DRIVER WITH DEAD-TIME CONTROL

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APPLICATION INFORMATION

Figure 17 shows the circuit schematic of a 100-kHz synchronous-buck converter implemented with a TL5001A pulse-width-modulation (PWM) controller and a TPS2837 driver. The converter operates over an input range from 4.5 V to 12 V and has a 3.3-V output. The circuit can supply 3 A continuous load and the transient load is 5 A. The converter achieves an efficiency of 94% for $V_{IN} = 5$ V, $I_{load} = 1$ A, and 93% for $V_{IN} = 5$ V, $I_{load} = 3$ A.

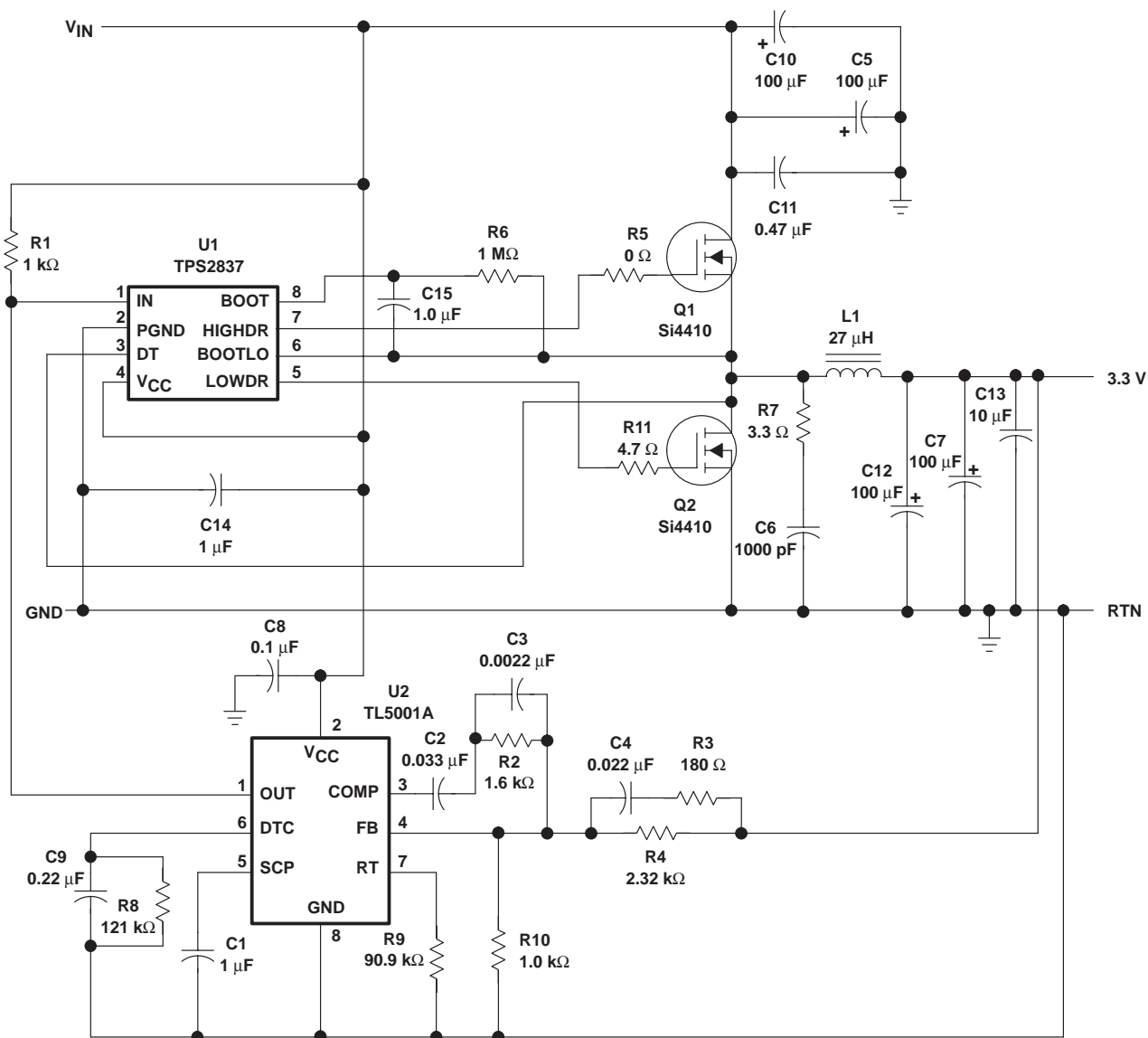


Figure 17. 3.3 V 3 A Synchronous-Buck Converter Circuit

APPLICATION INFORMATION

Great care should be taken when laying out the PC board. The power-processing section is the most critical and will generate large amounts of EMI if not properly configured. The junction of Q1, Q2, and L1 should be very tight. The connection from Q1 drain to the positive sides of C5, C10, and C11 and the connection from Q2 source to the negative sides of C5, C10, and C11 should be as short as possible. The negative terminals of C7 and C12 should also be connected to Q2 source.

Next, the traces from the MOSFET driver to the power switches should be considered. The BOOTLO signal from the junction of Q1 and Q2 carries the large gate drive current pulses and should be as heavy as the gate drive traces. The bypass capacitor (C14) should be tied directly across V_{CC} and PGND.

The next most sensitive node is the FB node on the controller (terminal 4 on the TL5001A). This node is very sensitive to noise pickup and should be isolated from the high-current power stage and be as short as possible. The ground around the controller and low-level circuitry should be tied to the power ground as the output. If these three areas are properly laid out, the rest of the circuit should not have other EMI problems and the power supply will be relatively free of noise.

TPS2836, TPS2837
SYNCHRONOUS-BUCK MOSFET DRIVER
WITH DEAD-TIME CONTROL

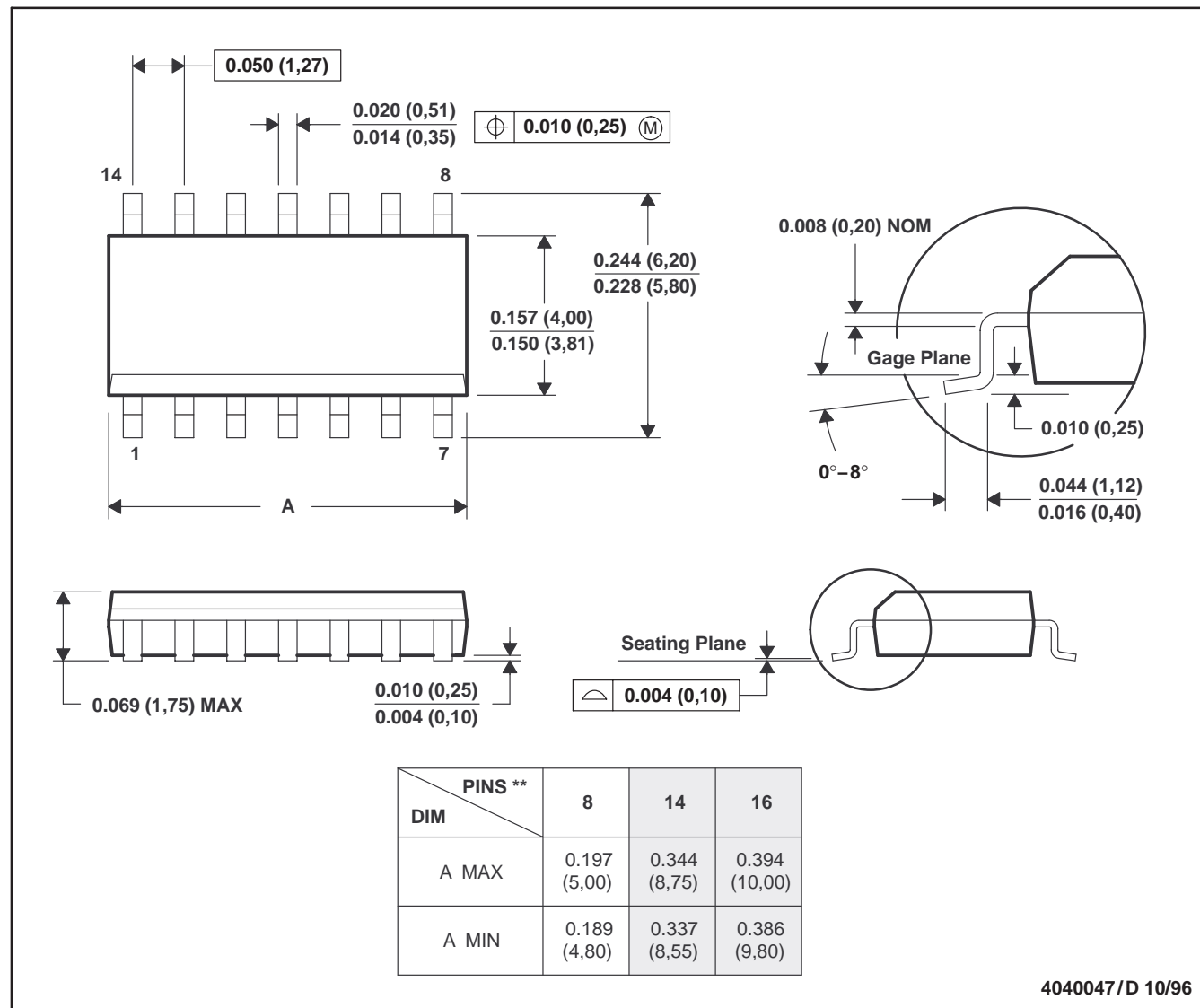
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MECHANICAL DATA

D (R-PDSO-G)**

PLASTIC SMALL-OUTLINE PACKAGE

14 PIN SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).
 D. Falls within JEDEC MS-012

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS2836D	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 125	2836
TPS2836DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2836
TPS2836DR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2836
TPS2837D	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 125	2837
TPS2837DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2837
TPS2837DR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2837

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS2836DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS2837DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS2836DR	SOIC	D	8	2500	340.5	338.1	20.6
TPS2837DR	SOIC	D	8	2500	353.0	353.0	32.0

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